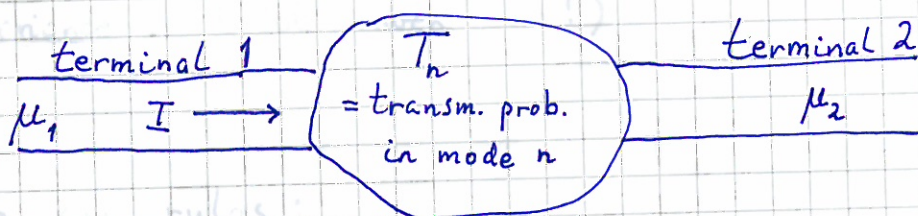


22.03.10

Büttiker - Landauer formalism

Recap, Landauer formula

(= "Two-terminal linear response formula") :



$$\mu_1 - \mu_2 = -e(V_1 - V_2) = -e \cdot \Delta V$$

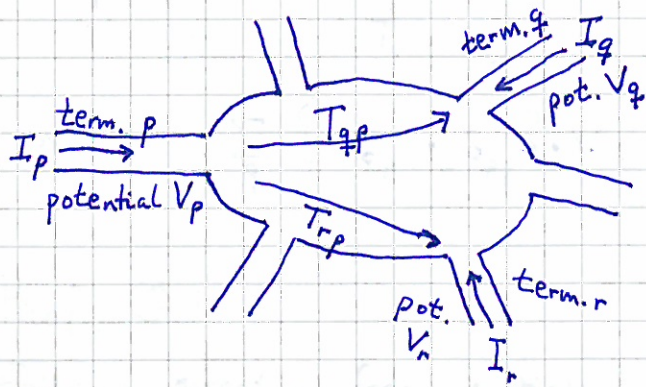
$$\begin{aligned} I &= \sum_n I_n = \left\{ \frac{2e^2}{h} \sum_n T_n(E_F) \right\} \cdot \Delta V = \frac{2e^2}{h} T(E_F) \cdot \Delta V \\ &= \left\{ \sum_n G_n \right\} \cdot \Delta V = G \cdot \Delta V \end{aligned}$$

May also write: $I_1 = \frac{2e^2}{h} \left\{ T_{2 \leftarrow 1} \cdot V_1 - T_{1 \leftarrow 2} \cdot V_2 \right\}$

with $T_{i \leftarrow j} \equiv T_{ij} = \sum_n T_n(E_F)$ = total trans. "sum" from term. j to i

Multi-terminal generalization by M. Büttiker (~1985):

(68)



M-term. device
(here: $M=6$)

$T_{qp} = T_{q \leftarrow p}$ = total
transm. sum from p to q

$$I_p = \left(-\frac{2e}{h}\right) \sum_q \left\{ T_{qp} \cdot \mu_p - T_{pq} \cdot \mu_q \right\}$$

$$= \frac{2e^2}{h} \sum_q \left\{ T_{qp} V_p - T_{pq} V_q \right\}$$

NB: $\sum_q$ means
 $\sum_{q \neq p}$

$$\Rightarrow \boxed{I_p = \sum_q \left\{ G_{qp} V_p - G_{pq} V_q \right\}} \quad \text{Büttiker formula}$$

Onsager symmetry relation:

$$G_{qp}(-\vec{B}) = G_{pq}(\vec{B}) \quad \left[\Rightarrow G_{qp} = G_{pq} \text{ if } \vec{B} = 0 \right]$$

Follows from particle conservation and time reversal invariance. (Not proven here!)

Two sum rules:

$$\textcircled{1} \quad \sum_q G_{qp} = \sum_q G_{pq}$$

$$\textcircled{2} \quad \sum_p I_p = 0$$

Proof, ①:

(69)

In equilibrium: $V_1 = V_2 = \dots = V_M = V$

$$I_1 = I_2 = \dots = I_M = 0$$

$$\Rightarrow 0 = \sum_f \{ G_{fp} - G_{pf} \} \cdot V \Rightarrow \sum_f G_{fp} = \sum_f G_{pf} \quad \underline{\text{qed}}$$

Proof, ②:

Follows directly from particle conservation!

Is also built into the formalism, since

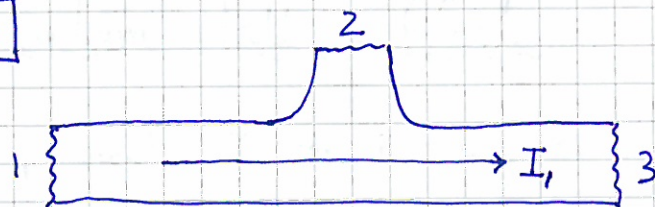
$$\sum_p \sum_{q \neq p} \{ G_{qp} V_p - G_{pq} V_q \} = 0 \quad (\text{trivially}) \quad \underline{\text{qed}}$$

Simplification via ①:

$$I_p = \sum_f G_{pf} (V_p - V_f) \quad \text{Büttiker formula}$$

Note: Only $M-1$ independent equations, since $\sum_p I_p = 0$

Example:



$$\text{Find } R_{13,23} = \left\{ (V_2 - V_3) / I_1 \right\}_{I_2=0}$$

$$[\text{Notation: } R_{\alpha\beta, \gamma\delta} = \frac{\text{voltage between term. } \gamma, \delta}{\text{current from term. } \alpha \text{ to term. } \beta}]$$

Solution:

$$\text{From Büttiker: } \begin{pmatrix} I_1 \\ I_2 \\ I_3 \end{pmatrix} = \begin{pmatrix} G_{12} + G_{13} & -G_{12} & -G_{13} \\ -G_{21} & G_{21} + G_{23} & -G_{23} \\ -G_{31} & -G_{32} & G_{31} + G_{32} \end{pmatrix} \begin{pmatrix} V_1 \\ V_2 \\ V_3 \end{pmatrix}$$

Only potential differences have physical relevance

$\Rightarrow$ we choose (e.g.) $V_3 = 0$

Also: $I_3 = -I_1 - I_2 \Rightarrow$ 3rd eqn. may be dropped

$$\Rightarrow \begin{pmatrix} I_1 \\ I_2 \end{pmatrix} = \begin{pmatrix} G_{12} + G_{13} & -G_{12} \\ -G_{21} & G_{21} + G_{23} \end{pmatrix} \begin{pmatrix} V_1 \\ V_2 \end{pmatrix}$$

Here: $I_2 = 0$

$$\Rightarrow I_1 = (G_{12} + G_{13})V_1 - G_{12}V_2$$

$$0 = -G_{21}V_1 + (G_{21} + G_{23})V_2$$

$$\Rightarrow I_1 = \left\{ (G_{12} + G_{13}) \cdot \frac{G_{21} + G_{23}}{G_{21}} - G_{12} \right\} V_2$$

$$\Rightarrow R_{13,23} = \frac{V_2}{I_1} = \frac{G_{21}}{G_{13}G_{21} + G_{12}G_{23} + G_{13}G_{23}}$$

$$[\text{Find } R_{23,13} = \left(\frac{V_1}{I_2} \right)_{I_1=0} !]$$

The Quantum Hall Effect

[First experiment: K. von Klitzing et al, 1980]

Edge states:

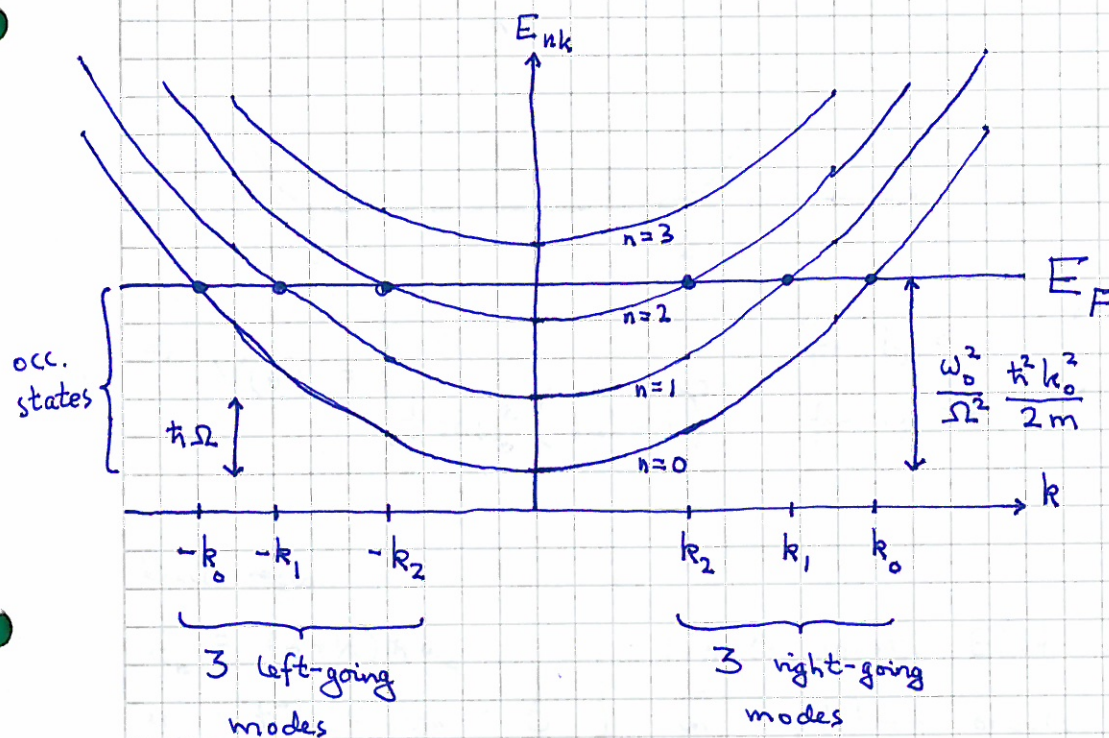
From Exercise 7:

$$V(y) = \frac{1}{2} m \omega_0^2 y^2, \quad \vec{A} = (-yB, 0, 0) \quad [\Rightarrow \vec{B} = \nabla \times \vec{A} = B \hat{z}]$$

$$\Rightarrow \psi_{nk} = e^{ikx} \phi_n \left(\frac{y - y_{nk}}{l_B} \right); \quad E_{nk} = \hbar \Omega (n + 1/2) + \frac{\omega_0^2}{\Omega^2} \frac{\hbar^2 k^2}{2m}$$

$$y_{nk} = k \cdot L_B^2 = k \cdot \frac{\omega_c^2}{\Omega^2} l_B^2 = k \cdot \frac{\omega_c^2}{\omega_c^2 + \omega_0^2} \cdot \frac{\hbar}{eB}$$

Transport takes place at $E_{nk} = E_F$:



⇒ This is similar to the 1D "waveguide":

1D subbands with DOS pr unit length

$$g_n^+(E) = g_n^-(E) = 2 / \hbar \cdot v_n(E)$$

$$\Rightarrow g_n^\pm(E) \cdot v_n(E) = \frac{2}{\hbar} = \text{const.}$$

⇒ Landauer/Büttiker formulas are OK!

Transverse location:

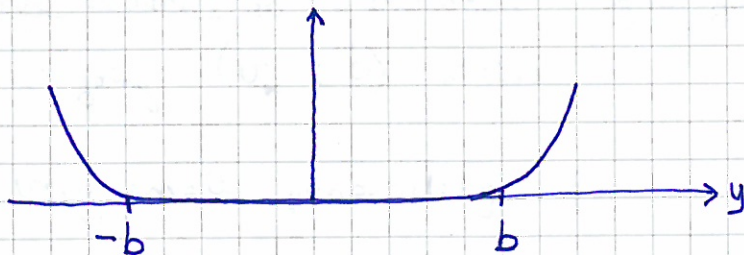
$$y_{nk} = k_n(E_F) \cdot L_B^2 = \pm \left\{ \frac{2m\Omega^2}{\hbar^2 \omega_0^2} [E_F - (n+1/2)\hbar\Omega] \right\}^{1/2} \cdot L_B^2$$

if $k > 0$, $y_{nk} > 0$ (and $y_{0k} > y_{1k} > y_{2k} > \dots$)

if $k < 0$, $y_{nk} < 0$

Since $\Phi_n((y - y_{nk})/l_B) \sim \exp\left\{-\frac{1}{2}\left(\frac{y - y_{nk}}{l_B}\right)^2\right\}$, these states are exponentially localized around $y = y_{nk}$, on length scale $\Delta y \sim l_B = \sqrt{\hbar/eB} \approx 30 \text{ nm}/\sqrt{B}$ (with B in tesla)

More typical confining potential:



$$\Rightarrow V(y) = \begin{cases} 0 & \text{for } |y| < b \quad (\text{"bulk region"}) \\ \frac{1}{2} m \omega_c^2 (|y| - b)^2 & \text{for } |y| > b \quad (\text{"edge region"}) \end{cases}$$

Bulk region:

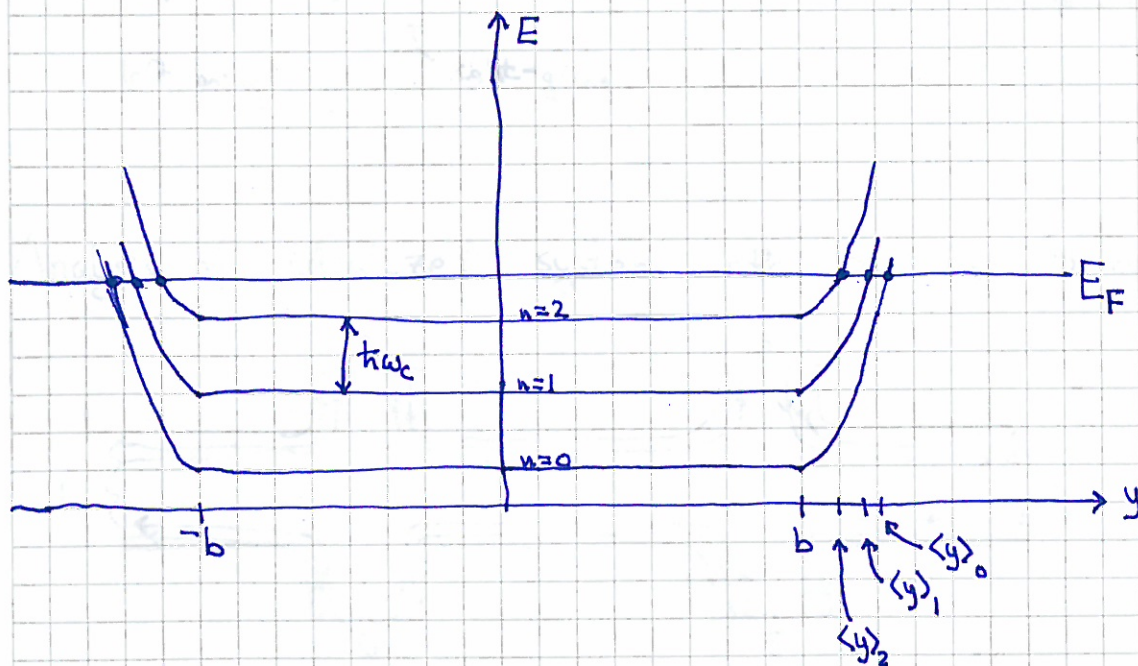
$$\left. \begin{aligned} E_n &= (n + \frac{1}{2}) \hbar \omega_c \\ v_n &= \hbar^{-1} \partial E_n / \partial k = 0 \end{aligned} \right\} \begin{array}{l} \text{No transport. Electrons are circulating} \\ \text{in cyclotron orbits.} \end{array}$$

Edge region:

$$E_{nk} = (n + \frac{1}{2}) \hbar \Omega + \frac{\hbar^2 k^2}{2M_B}$$

$$v_n(k) = \hbar k / M_B$$

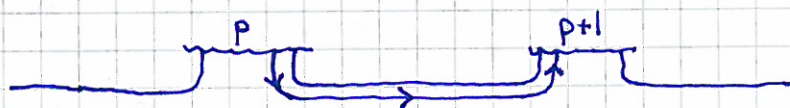
$$y_{nk} = b + k L_B^2 = \langle y \rangle_n \quad \text{for edge state } \psi_{nk} \quad (\text{at } E_{nk} = E_F)$$



Most important consequence of this is the Large separation between right-going ($v_x > 0$) and left-going ($v_x < 0$) states

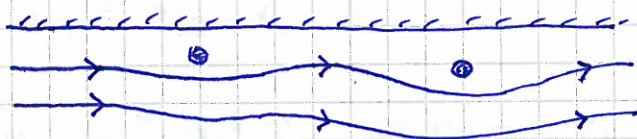
⇒ very small probability for back-scattering!

⇒ an electron that emerges from one terminal in an edge state has probability ≈ 1 for ending up in the neighbouring terminal:



This requires ideal terminals: $T_{p+1,p} \approx 1$

Robust with respect to impurity scattering:



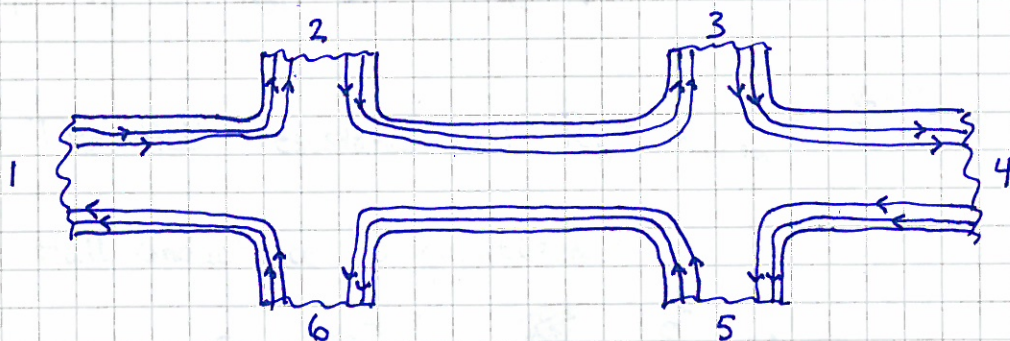
● = impurity; local potential $V_i(\vec{r})$

Back-scattering probability:

$$|\langle n | V_i | m \rangle|^2 \approx 0 \quad (\text{exponentially small})$$

$\uparrow$ left-going $\uparrow$ right-going

Analysis of idealized system with Büttiker formula:



2, 3, 5, 6: Voltage probes $\Rightarrow I_2 = I_3 = I_5 = I_6 = 0$

1, 4: Source and drain $\Rightarrow I = I_1 = I_{1 \rightarrow 4} = -I_4$

$V_1 - V_4 =$ applied voltage ("bias")

N edge states (in each direction) below E_F

$$\Rightarrow G = \frac{2e^2}{h} \cdot N$$

$$R_{14,14} = R_{2t} = \frac{1}{G} = \frac{h}{2e^2} \cdot \frac{1}{N} \quad (2\text{-term. resistance})$$

Buttiker: $I_p = \sum_{q \neq p} G_{pq} (V_p - V_q)$

with $G_{21} = G_{32} = G_{43} = G_{54} = G_{65} = G_{16} = \frac{2e^2}{h} \cdot N$

$$G_{12} = G_{23} = \dots = 0$$

$$\Rightarrow I_2 = G_{21} (V_2 - V_1)$$

$$I_3 = G_{32} (V_3 - V_2)$$

Since $I_2 = I_3 = 0$, we have $V_1 = V_2 = V_3$

$$\Rightarrow \underline{R_L} = R_{14,23} = \frac{V_2 - V_3}{I} = \underline{\underline{0}}$$

[This is the classical result, which is correct for small $\vec{B}$.]

Similarly, since $I_5 = I_6 = 0 \Rightarrow$ $V_4 = V_5 = V_6$

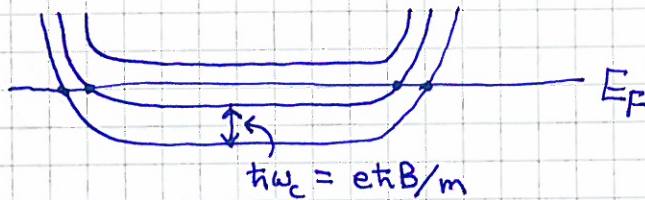
$$V_1 - V_4 = R_{2t} \cdot I = \frac{h}{2e^2 \cdot N} \cdot I$$

$$\Rightarrow \text{The Hall resistance is: } R_H = R_{14,26} = \frac{V_2 - V_6}{I} = \frac{V_1 - V_4}{I} = \frac{h}{2e^2 \cdot N}$$

$\Rightarrow$ Hall conductance is quantized:

$$G_H = R_H^{-1} = \frac{2e^2}{h} \cdot N$$

How will G_H depend on B ?



$$(N + 1/2) e\hbar B/m < E_F < (N + 3/2) e\hbar B/m$$

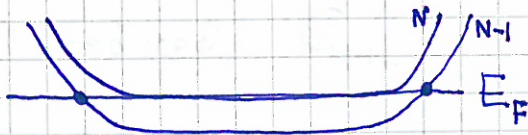
$$\Rightarrow N(B) \sim \left[\frac{m E_F}{e\hbar B} \right] = \left[\frac{\text{const}}{B} \right]$$

($[\dots]$ = integer part of $\dots$)

$\Rightarrow$ when B increases, $N \rightarrow \text{N-1}$ each time a Landau level rises above E_F



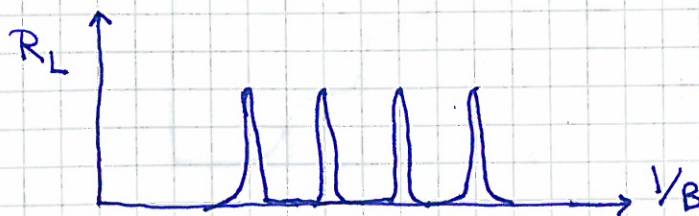
Near transition between two plateaus: $E_F = (N + 1/2) \hbar\omega_c$



Edge States in LL $N-1$ are well separated, but LL N extends across sample in transverse direction

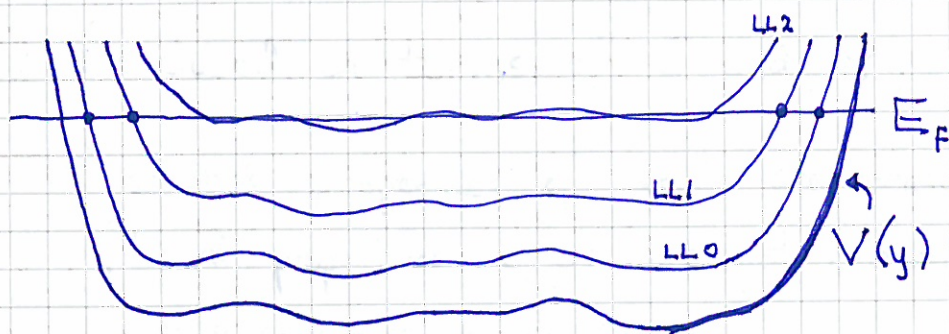
$\Rightarrow$ severely increased prob. for back-scattering in LL N

$\Rightarrow R_L \neq 0$ near transitions; $R_L \approx 0$ on " R_H -plateaus":



SdH oscillations,
periodic in $1/B$

A more realistic situation:

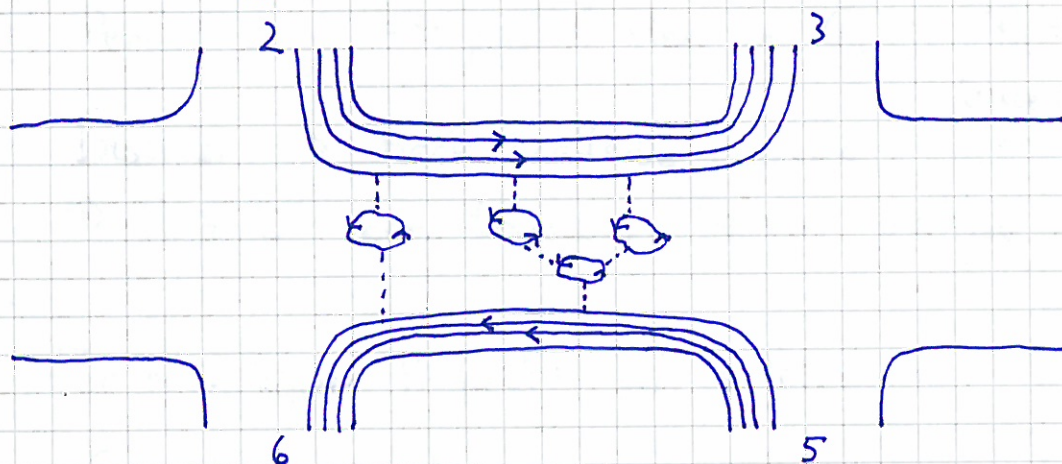


⇒ both localized and extended states are possible at E_F

No back-scattering in LL0 and LL1.

Back-scattering possible in LL2 when $E_{LL2}^{bulk} \approx E_F$

Schematically:



⇒ reduced $G_{p+1,p}$ (e.g. G_{32} , G_{65})

⇒ $V_2 > V_3$ etc.

⇒ $R_L = (V_2 - V_3) / I > 0$

and $G_H < \frac{2e^2}{h} N$ when transition is approached:

